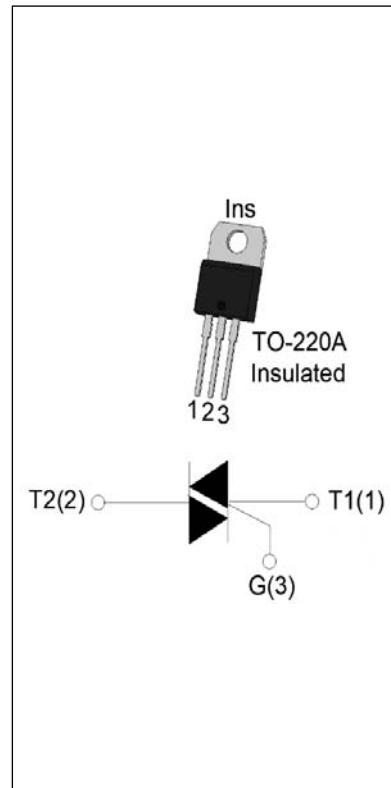


**DESCRIPTION:**

The JST24A-800CW triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. JST24A-800CW snubberless triac is especially recommended for use on inductive loads. By using an internal ceramic pad, JST24A-800CW provides a rated insulation voltage of 2500 VRMS, complying with UL standards (File ref: E252906). Package TO-220A is RoHS compliant.

**MAIN FEATURES**

Symbol	Value	Unit
$I_{T(RMS)}$	25	A
$V_{DRM}/V_{RRM}$	800	V
$I_{GT\text{ I/II/III}}$	35/35/35	mA

**ABSOLUTE MAXIMUM RATINGS**

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	°C
Operating junction temperature range	$T_j$	-40-125	°C
Repetitive peak off-state voltage ( $T_j=25^\circ\text{C}$ )	$V_{DRM}$	800	V
Repetitive peak reverse voltage ( $T_j=25^\circ\text{C}$ )	$V_{RRM}$	800	V
RMS on-state current ( $T_c \leq 79^\circ\text{C}$ )	$I_{T(RMS)}$	25	A
Non repetitive surge peak on-state current (full cycle , $t_p=20\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I_{TSM}$	250	A
Non repetitive surge peak on-state current (full cycle , $t_p=16.6\text{ms}$ , $T_j=25^\circ\text{C}$ )		275	
$I^2t$ value for fusing ( $t_p=10\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I^2t$	340	$\text{A}^2\text{s}$
Critical rate of rise of on-state current ( $I_G=2 \times I_{GT}$ , $f=100\text{Hz}$ , $T_j=125^\circ\text{C}$ )	$dI/dt$	100	$\text{A}/\mu\text{s}$
Peak gate current ( $t_p=20\mu\text{s}$ , $T_j=125^\circ\text{C}$ )	$I_{GM}$	4	A
Average gate power dissipation ( $T_j=125^\circ\text{C}$ )	$P_{G(AV)}$	0.5	W

Peak gate power	$P_{GM}$	10	W
Peak pulse voltage ( $T_j=25^\circ C$ ; non-repetitive, off-state; FIG.7)	$V_{pp}$	2.5	kV

**ELECTRICAL CHARACTERISTICS** ( $T_j=25^\circ C$  unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
$I_{GT}$	$V_D=12V R_L=33\Omega$	I - II - III	MAX.	35	mA
$V_{GT}$		I - II - III	MAX.	1	V
$V_{GD}$	$V_D=V_{DRM} T_j=125^\circ C$ $R_L=3.3K\Omega$	I - II - III	MIN.	0.2	V
$I_L$	$I_G=1.2I_{GT}$	I - III	MAX.	70	mA
		II		80	
$I_H$	$I_T=500mA$		MAX.	50	mA
$dV/dt$	$V_D=540V$ Gate Open $T_j=125^\circ C$		MIN.	1200	V/ $\mu$ s
$(dI/dt)c$	$(dV/dt)c=20V/\mu s$ $T_j=125^\circ C$		MIN.	15	A/ms
$t_{on}$	$I_G=40mA I_A=200mA I_R=20mA$ $T_j=25^\circ C$	TYP.		7	$\mu$ s
				50	

**STATIC CHARACTERISTICS**

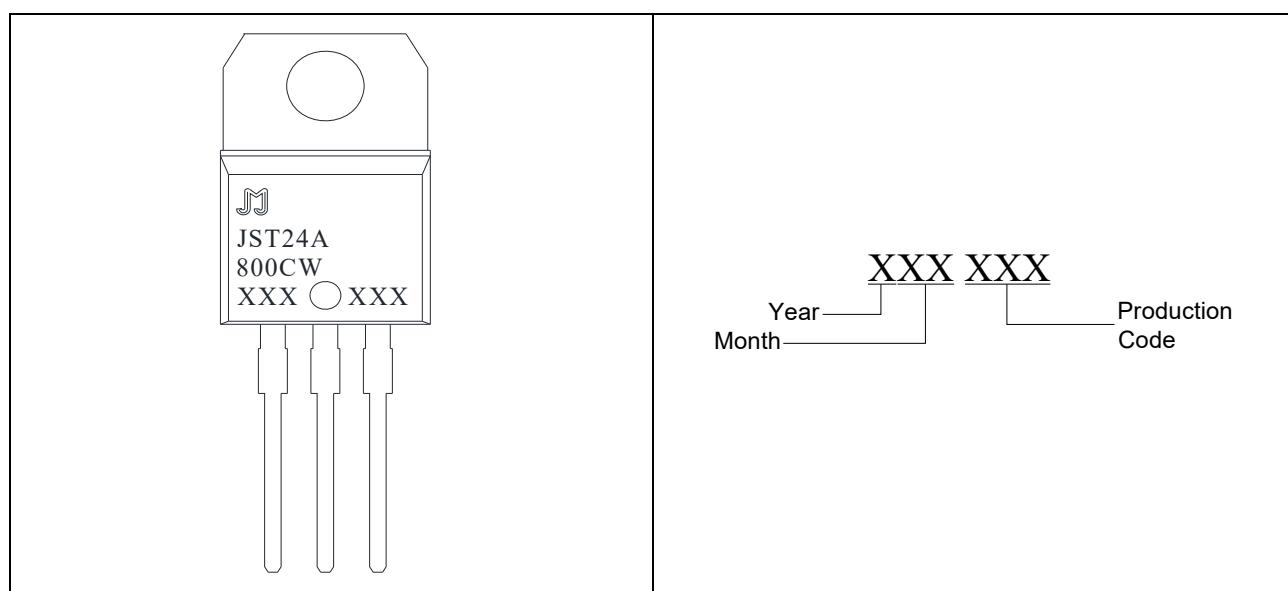
Symbol	Parameter		Value(MAX.)	Unit	
$V_{TM}$	$I_{TM}=35A$	$t_p=380\mu s$	$T_j=25^\circ C$	1.5	V
$V_{TO}$	Threshold voltage		$T_j=125^\circ C$	0.75	V
$R_D$	Dynamic resistance		$T_j=125^\circ C$	18	m $\Omega$
$I_{DRM}$	$V_D=V_{DRM}$	$V_R=V_{RRM}$	$T_j=25^\circ C$	5	$\mu A$
$I_{RRM}$			$T_j=125^\circ C$	2	mA

**THERMAL RESISTANCES**

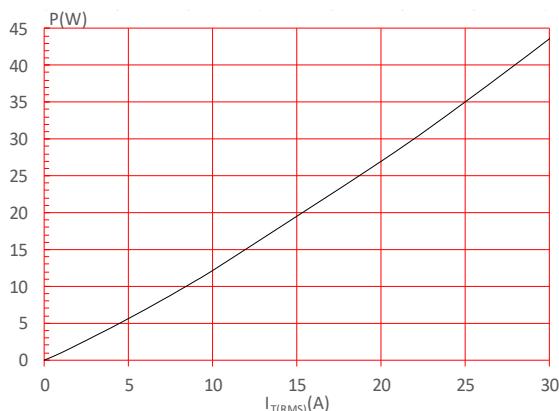
Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (AC)	1.3	$^\circ C/W$
$R_{th(j-a)}$	junction to ambient (AC)	60	$^\circ C/W$

**ORDERING INFORMATION**

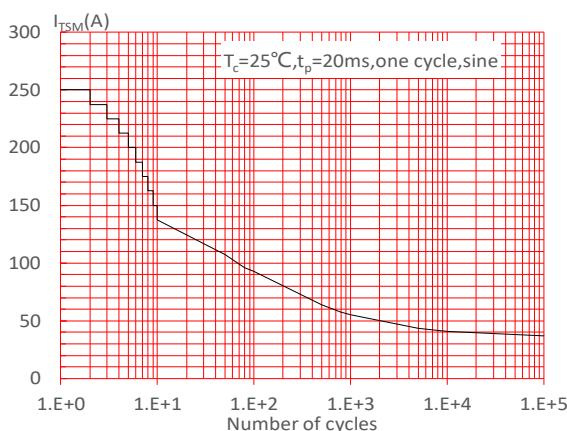
<u>J</u>	<u>ST</u>	<u>24</u>	<u>A</u>	<u>-800</u>	<u>CW</u>
JieJie Microelectronics Co., Ltd.					
	Triacs				
		<u><math>I_{T(RMS)}:25A</math></u>			
			<u>A:TO-220A(Ins)</u>		
				<u>CW:<math>I_{GT1-3} \leq 35mA</math></u>	
				<u>800:<math>V_{DRM} / V_{RRM} \geq 800V</math></u>	

**MARKING**

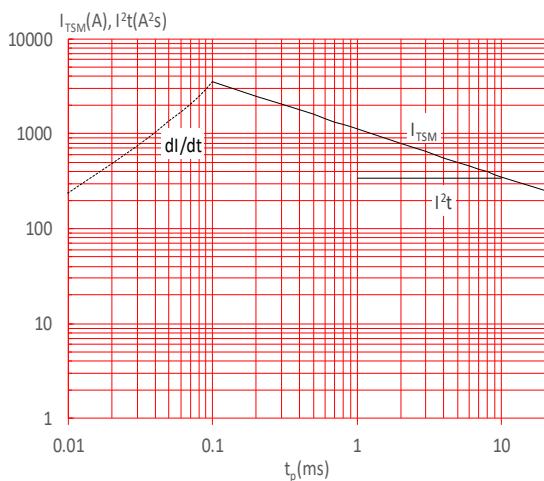
**FIG.1 Maximum power dissipation versus RMS on-state current**



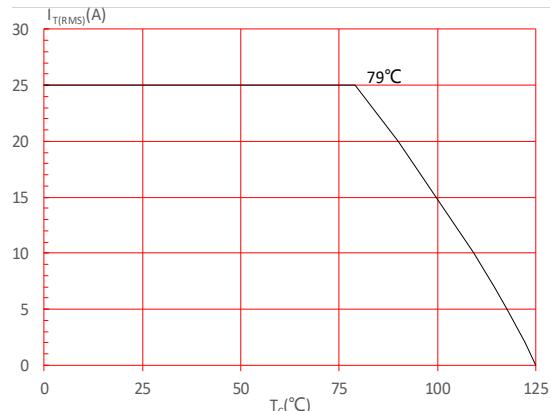
**FIG.3: Surge peak on-state current versus number of cycles**



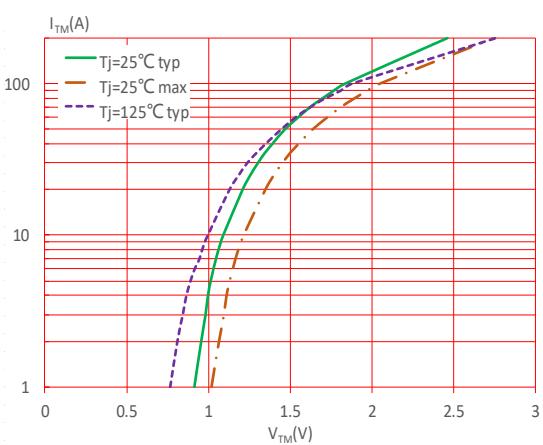
**FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 20\text{ms}$ , and corresponding value of  $I^2t$  ( $dI/dt < 100\text{A}/\mu\text{s}$ )**



**FIG.2: RMS on-state current versus case temperature**



**FIG.4: On-state characteristics**



**FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature**

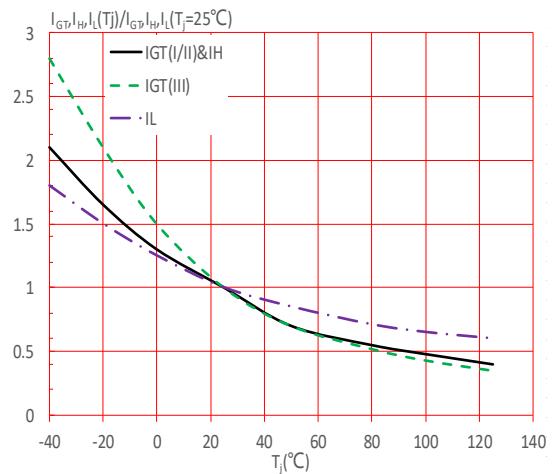
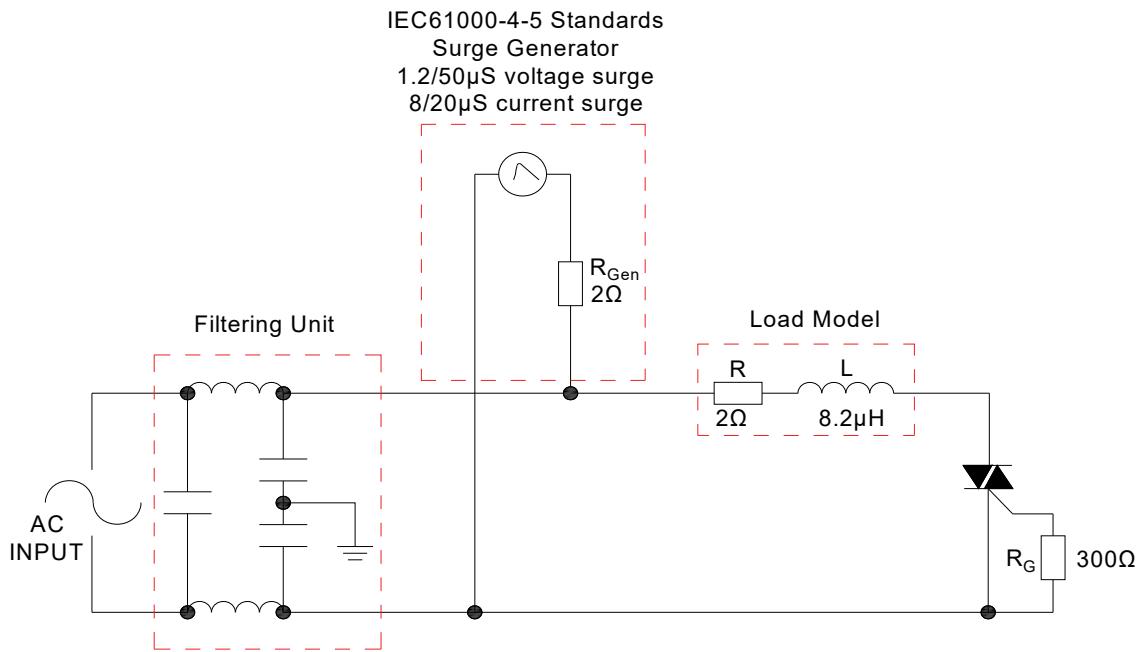


FIG.7: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



## SHAPING AND SOLDERING PARAMETERS

Refer to 《Instructions for installation of plastic-sealed in-line power devices》 released by JieJie

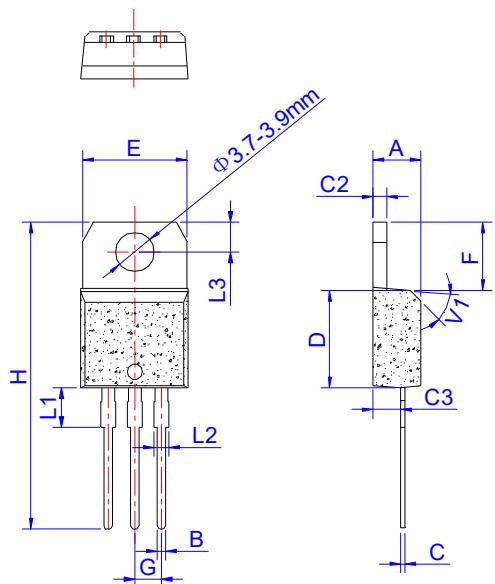
**ORDERING INFORMATION**

Order code	Voltage $V_{DRM}/V_{RRM}(V)$	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		I -II-III			
<b>JST24A-800CW</b>	<b>800</b>	<b>35</b>	<b>TO-220A(Ins)</b>	<b>50</b>	<b>Tube</b>

**Document Revision History**

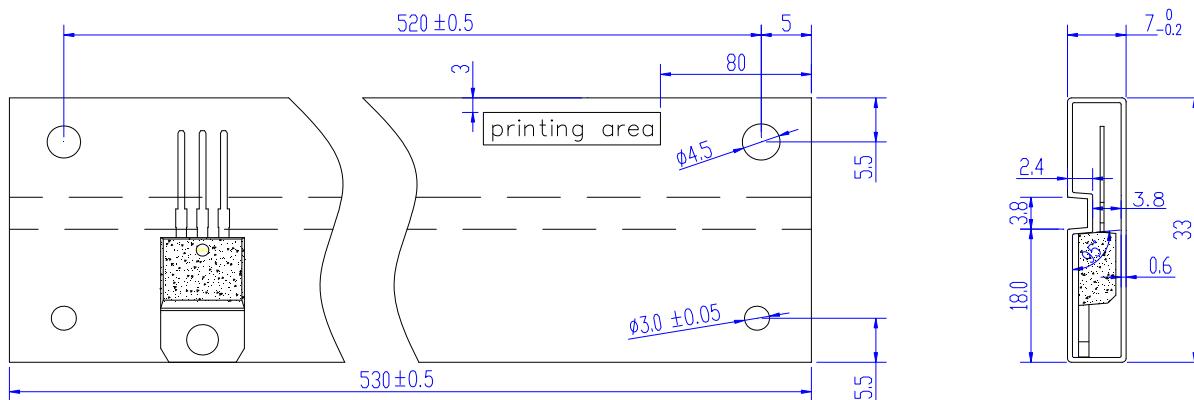
Date	Revision	Changes
Apr.12, 2023	A.1.0	Last updated

## PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.80		10.4	0.386		0.409
F	6.25		6.85	0.246		0.270
G	2.40		2.70	0.094		0.106
H	28.0		29.8	1.102		1.173
L1	3.45		4.05	0.136		0.159
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

## DELIVERY MODE



PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-220A	TUBE	50	1,000	5,000

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